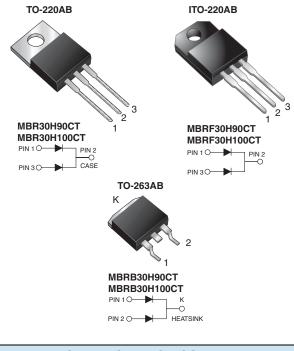
MBR30HxxCT, MBRF30HxxCT, MBRB30HxxCT

Vishay General Semiconductor

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



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ISHA

PRIMARY CHARACTERISTICS					
I _{F(AV)}	15 A x 2				
V _{RRM}	90 V to 100 V				
I _{FSM}	275 A				
V _F	0.67 V				
I _R	5.0 µA				
T _J max.	175 °C				
Package	TO-220AB, ITO-220AB, TO-263AB				
Diode variations	Dual common cathode				

FEATURES

- Power pack
- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
 Automotive ordering code: base P/NHE3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_C = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER		SYMBOL	MBR30H90CT	MBR30H100CT	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	90	100		
Working peak reverse voltage		V _{RWM}	90	100	V	
Maximum DC blocking voltage		V _{DC}	90	100		
Maximum average forward rectified current (fig.1)	total device	I	30 15			
	per diode	I _{F(AV)}				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	275		А	
Peak repetitive reverse surge current per diode at $t_p = 2.0 \ \mu s$, 1 kHz		I _{RRM}	1.0			
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs	
Operating junction and storage temperature rang	e	T _J , T _{STG}	-65 to) +175	°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500		V	

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ELECTRICAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V _F (1)	I _F = 15 A	T _J = 25 °C	0.82	- V	
		I _F = 15 A	T _J = 125 °C	0.67		
		I _F = 30 A	T _J = 25 °C	0.93		
		I _F = 30 A	T _J = 125 °C	0.80		
Maximum reverse current per diode	I _R ⁽²⁾	Rated V _R	T _J = 25 °C	5.0	μA	
			T _J = 125 °C	6.0	mA	

Note

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width, \leq 40 ms

THERMAL CHARACTERISTICS ($T_c = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance per diode	$R_{ ext{ heta}JC}$	1.9	4.6	1.9	°C/W

ORDERING IN	FORMATION (Example)				
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	MBR30H100CT-E3/45	1.85	45	50/tube	Tube
ITO-220AB	MBRF30H100CT-E3/45	1.99	45	50/tube	Tube
TO-263AB	MBRB30H100CT-E3/45	1.35	45	50/tube	Tube
TO-263AB	MBRB30H100CT-E3/81	1.35	81	800/reel	Tape and reel
TO-220AB	MBR30H100CTHE3/45 ⁽¹⁾	1.85	45	50/tube	Tube
ITO-220AB	MBRF30H100CTHE3/45 1)	1.99	45	50/tube	Tube
TO-263AB	MBRB30H100CTHE3/45 (1)	1.35	45	50/tube	Tube
TO-263AB	MBRB30H100CTHE3/81 (1)	1.35	81	800/reel	Tape and reel

Note

(1) AEC-Q101 qualified



MBR30HxxCT, MBRF30HxxCT, MBRB30HxxCT

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RATINGS AND CHARACTERISTICS CURVES ($T_C = 25$ °C unless otherwise noted)

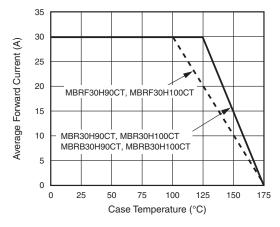


Fig. 1 - Forward Derating Curve Per Diode

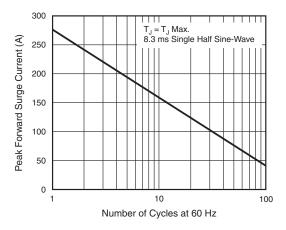


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

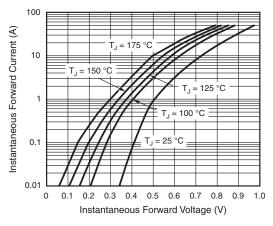


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

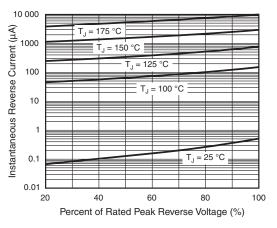


Fig. 4 - Typical Reverse Characteristics Per Diode

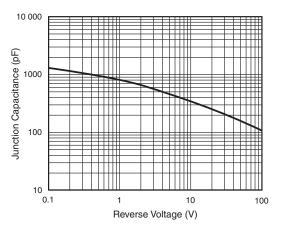


Fig. 5 - Typical Junction Capacitance Per Diode

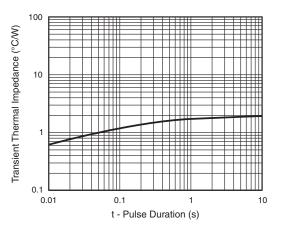


Fig. 6 - Typical Transient Thermal Impedance Per Diode

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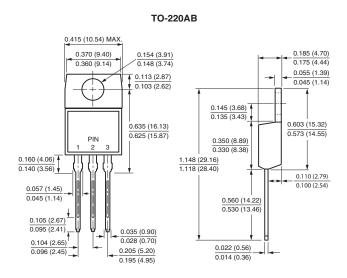
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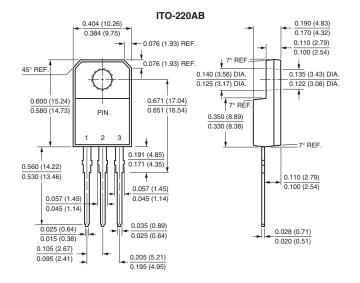


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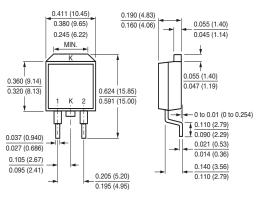
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

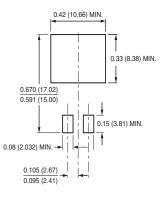




TO-263AB



Mounting Pad Layout





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